

1.1 Scope.

This specification covers the detail requirements for a high speed, low power operational amplifier that is stable at closed loop gains of 25 or greater.

1.2 Part Number.

The complete part number per Table 1 of this specification is as follows:

Device	Part Number
-1	AD849SQ/883B

1.2.3 Case Outline.

See Appendix 1 of General Specification ADI-M-1000: package outline: Q-8.

1.3 Absolute Maximum Ratings. ($T_A = +25^\circ\text{C}$ unless otherwise noted)

Supply Voltage	$\pm 18 \text{ V}$
Internal Power Dissipation ¹	1.1 W
Input Common-Mode Voltage, Max Safe	$\pm V_S$
Differential Input Voltage	$\pm 6 \text{ V}$
Rated Operating Temperature Range	-55°C to $+125^\circ\text{C}$
Storage Temperature Range	-65°C to $+150^\circ\text{C}$
Lead Temperature (Soldering 60 sec)	+300°C

NOTE

¹Maximum internal power dissipation is specified so the T_J does not exceed $+175^\circ\text{C}$ at an ambient temperature of $+25^\circ\text{C}$. Derates at $7.3 \text{ mW}/^\circ\text{C}$.

1.5 Thermal Characteristics.

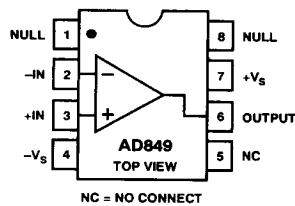
Thermal Resistance $\theta_{JA} = 110^\circ\text{C}/\text{W}$
 $\theta_{JC} = 30^\circ\text{C}/\text{W}$

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Table 1.

Test	Symbol	Device	Sub Group 1	Sub Group 2, 3	V_S	Test Conditions	Unit
Input Offset Voltage	V_{OS}	-1	0.75	1.0	$\pm 5 \text{ V}, \pm 15 \text{ V}$		$\pm \text{mV} \text{ max}$
Input Bias Current	I_B	-1	5	7.5	$\pm 5 \text{ V}, \pm 15 \text{ V}$	$V_{CM} = 0 \text{ V}$	$\pm \mu\text{A} \text{ max}$
Input Offset Current	I_{OS}	-1	0.3	0.4	$\pm 5 \text{ V}, \pm 15 \text{ V}$		$\pm \mu\text{A} \text{ max}$
Open Loop Gain	A_{OL}	-1	30	15	$\pm 5 \text{ V}$	$V_{OUT} = \pm 2.5 \text{ V}, R_{LOAD} = 500 \Omega$	V/mV min
			45	25	$\pm 15 \text{ V}$	$V_{OUT} = \pm 10 \text{ V}, R_{LOAD} = 1 \text{k}\Omega$	
Common-Mode Rejection Ratio	CMRR	-1	100	96	$\pm 5 \text{ V}$	$V_{CM} = \pm 2.5 \text{ V}$	dB min
		-1	100	96	$\pm 15 \text{ V}$	$V_{CM} = \pm 12 \text{ V}$	
Output Voltage Swing	V_{OUT}	-1	3 2.5 12 10		$\pm 5 \text{ V}$ $\pm 5 \text{ V}$ $\pm 15 \text{ V}$ $\pm 15 \text{ V}$	$R_{LOAD} = 500 \Omega$ $R_{LOAD} = 150 \Omega$ $R_{LOAD} = 1 \text{k}\Omega$ $R_{LOAD} = 500 \Omega$	$\pm \text{V min}$
Power Supply Rejection Ratio	PSRR	-1	98	94		$V_S = \pm 4.5 \text{ V} \text{ to } \pm 18 \text{ V}$	dB min
Power Supply Current	I_Q	-1	6.0 6.8	8.3 9.0	$\pm 5 \text{ V}$ $\pm 15 \text{ V}$	$V_{OUT} = 0 \text{ V}$ $V_{OUT} = 0 \text{ V}$	mA max

3.2.1 Functional Block Diagram and Terminal Assignments.



3.2.4 Microcircuit Technology Group.

This microcircuit is covered by technology group (85).

4.2.1 Life Test/Burn-in Circuit.

Steady state life test is per MIL-STD-883 Method 1005. Burn-in is per MIL-STD-883 Method 1015 test condition (B).

